

**Product data sheet** 

### **1. General description**

Planar passivated Silicon Controlled Rectifier (SCR) with sensitive gate in a SOT89 surface mountable plastic package. This SCR is designed to be interfaced directly to microcontrollers, logic integrated circuits and other low power gate trigger circuits.

## 2. Features and benefits

- · Sensitive gate
- High voltage capability
- · Planar passivated for voltage ruggedness and reliability
- Surface mountable package

## **3. Applications**

- Ground Fault Circuit Interrupters (GFCI)
- General purpose switching and phase control
- Ignition circuits, CDI for 2- and 3-wheelers
- Motor control-e.g. small kitchen appliances

### 4. Quick reference data

Symbol	Parameter	Conditions	Values	Unit
Absolute m	aximum rating			
V <sub>RRM</sub>	repetitive peak reverse voltage		600	V
I <sub>T(RMS)</sub>	RMS on-state current	half sine wave; T <sub>sp</sub> ≤ 109 °C; <u>Fig. 1; Fig. 2; Fig. 3</u>	0.8	A
I <sub>TSM</sub>	non-repetitive peak on- state current	half sine wave; $T_{j(init)} = 25 \text{ °C}$ ; $t_p = 10 \text{ ms}$ ; Fig. 4; Fig. 5	8	A
		half sine wave; $T_{j(init)}$ = 25 °C; $t_p$ = 8.3 ms	9	A
T <sub>j</sub>	junction temperature		125	°C

# NCR100Q-6M

SCR

Symbol	Parameter	Conditions		Min	Тур	Max	Unit	
Static cha	Static characteristics							
I <sub>GT</sub>	gate trigger current	$V_{\rm D}$ = 12 V; I <sub>T</sub> = 0.1 A; T <sub>j</sub> = 25 °C; <u>Fig. 7</u>		15	-	100	μA	
I <sub>H</sub>	holding current	$V_{D}$ = 12 V; T <sub>j</sub> = 25 °C; R <sub>GK(ext)</sub> = 1 kΩ; Fig. 9		-	-	5	mA	
V <sub>T</sub>	on-state voltage	I <sub>T</sub> = 1.6 A; T <sub>j</sub> = 25 °C; <u>Fig. 10</u>		-	1.4	1.7	V	
Dynamic characteristics								
dV <sub>D</sub> /dt	rate of rise of off-state voltage	$V_{DM}$ = 600 V; T <sub>j</sub> = 125 °C; R <sub>GK</sub> = 1 kΩ; exponential waveform		100	-	-	V/µs	

# 5. Pinning information

Table 2. P	inning infor	mation		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate	mb	
2	А	anode		А-Ӈ-К
3	К	cathode		G sym037
mb	mb	mounting base; connected to anode		

# 6. Ordering information

Table 3. Ordering information								
Type number	Package Name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date		
NCR100Q-6M	SOT89	NCR100Q-6MJ	Reel	1000	SOT89L	8-Mar-2019		

# 7. Marking

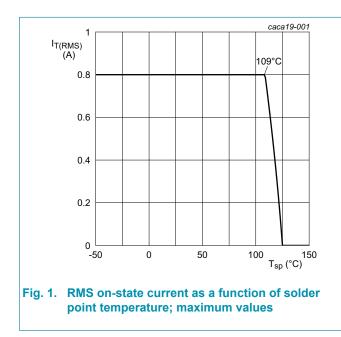
Table 4. Marking codes								
Type number	Marking codes							
NCR100Q-6M	NCR1006M							

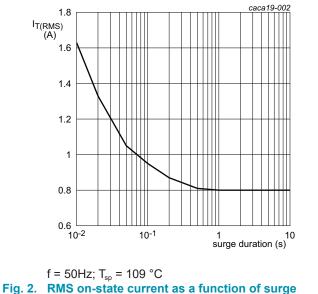
# 8. Limiting values

### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Values	Unit
$V_{\text{DRM}}$	repetitive peak off-state voltage		600	V
$V_{\text{RRM}}$	repetitive peak reverse voltage		600	V
I <sub>T(AV)</sub>	average on-state current	half sine wave; $T_{sp} \le 109 \text{ °C}$	0.51	A
I <sub>T(RMS)</sub>	RMS on-state current	half sine wave; T <sub>sp</sub> ≤ 109 °C; <u>Fig. 1; Fig. 2; Fig. 3</u>	0.8	A
I <sub>TSM</sub>	non-repetitive peak on- state current	half sine wave; T <sub>j(init)</sub> = 25 °C; t <sub>p</sub> = 10 ms; Fig. 4; Fig. 5	8	A
		half sine wave; $T_{j(init)}$ = 25 °C; $t_p$ = 8.3 ms	9	А
l <sup>2</sup> t	I <sup>2</sup> t for fusing	t <sub>p</sub> = 10ms; sine wave	0.32	A <sup>2</sup> s
dl <sub>⊤</sub> /dt	rate of rise of on-state current	I <sub>G</sub> = 0.2 mA	50	A/µs
I <sub>GM</sub>	peak gate current		1	A
$V_{\text{GM}}$	peak gate voltage		5	V
P <sub>GM</sub>	peak gate power		2	W
P <sub>G(AV)</sub>	average gate power	over any 20 ms period	0.1	W
T <sub>stg</sub>	storage temperature		-40 to 150	°C
Tj	junction temperature		125	°C







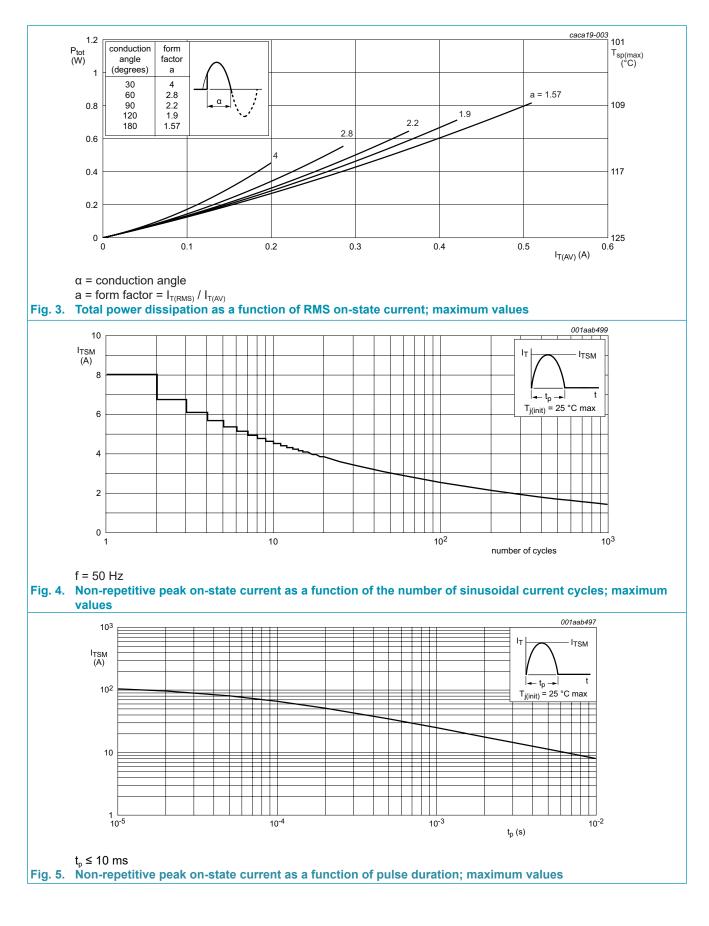
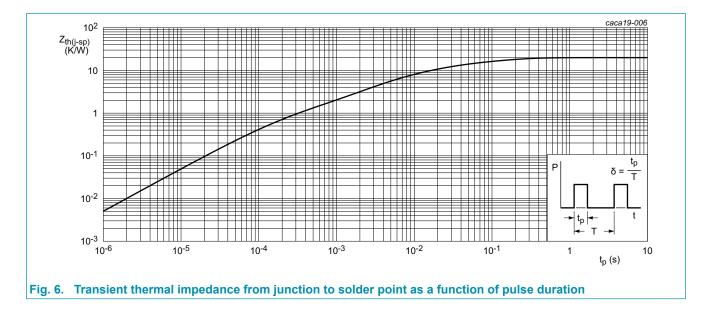


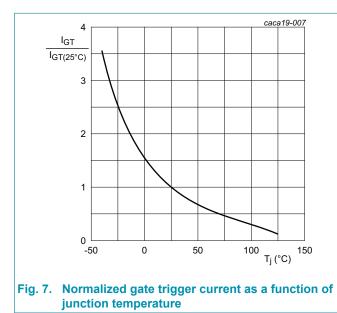
Table 6. Thermal characteristics							
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$R_{th(j-sp)}$	thermal resistance from junction to solder point	<u>Fig. 6</u>		-	-	20	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient free air	in free air		-	90	-	K/W

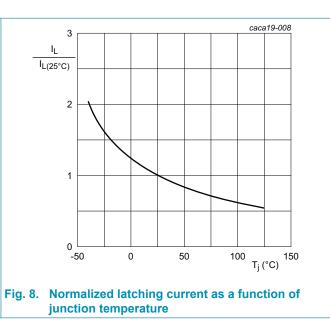




## **10. Characteristics**

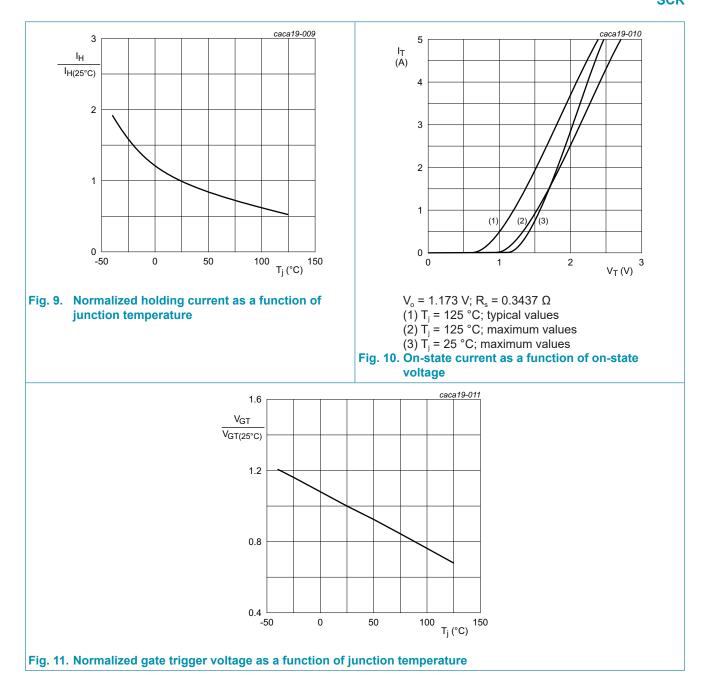
Table 7. Ch	naracteristics						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Static cha	racteristics		·				
I <sub>GT</sub>	gate trigger current	V <sub>D</sub> = 12 V; I <sub>T</sub> = 0.1 A; T <sub>j</sub> = 25 °C; <u>Fig. 7</u>		15	-	100	μA
I <sub>L</sub>	latching current	$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T}_{j} = 25 \text{ °C};$ $R_{GK(ext)} = 1 \text{ k}\Omega; \text{ Fig. 8}$		-	-	6	mA
I <sub>H</sub>	holding current	$V_D = 12 \text{ V};  \text{T}_\text{j} = 25 ^\circ\text{C};$ $R_{GK(ext)} = 1  \text{k}\Omega;  \text{Fig. 9}$		-	-	5	mA
V <sub>T</sub>	on-state voltage	I <sub>T</sub> = 1.6 A; T <sub>j</sub> = 25 °C; <u>Fig. 10</u>		-	1.4	1.7	V
V <sub>GT</sub>	gate trigger voltage	V <sub>D</sub> = 12 V; I <sub>T</sub> = 0.1 A; T <sub>j</sub> = 25 °C; <u>Fig. 11</u>		-	0.7	1	V
		V <sub>D</sub> = 600 V; I <sub>T</sub> = 0.1 A; T <sub>j</sub> = 125 °C		0.2	0.5	-	V
I <sub>D</sub>	off-state current	V <sub>D</sub> = 600 V; T <sub>j</sub> = 125 °C		-	-	0.1	mA
I <sub>R</sub>	reverse current	V <sub>D</sub> = 600 V; T <sub>j</sub> = 125 °C		-	-	0.1	mA
Dynamic o	characteristics						
dV <sub>D</sub> /dt	rate of rise of off-state voltage	$V_{DM}$ = 600 V; T <sub>j</sub> = 125 °C; R <sub>GK</sub> = 1 kΩ; exponential waveform		100	-	-	V/µs
t <sub>gt</sub>	gate-controlled turn-on time	$I_{TM} = 2 \text{ A}; V_D = 600 \text{ V}; I_G = 1 \text{ mA};$ $(dI_G/dt)_M = 0.1 \text{ A}/\mu\text{s}; T_j = 25 \text{ °C}$		-	2	-	μs
t <sub>q</sub>	commutated turn-off time			-	100	-	μs



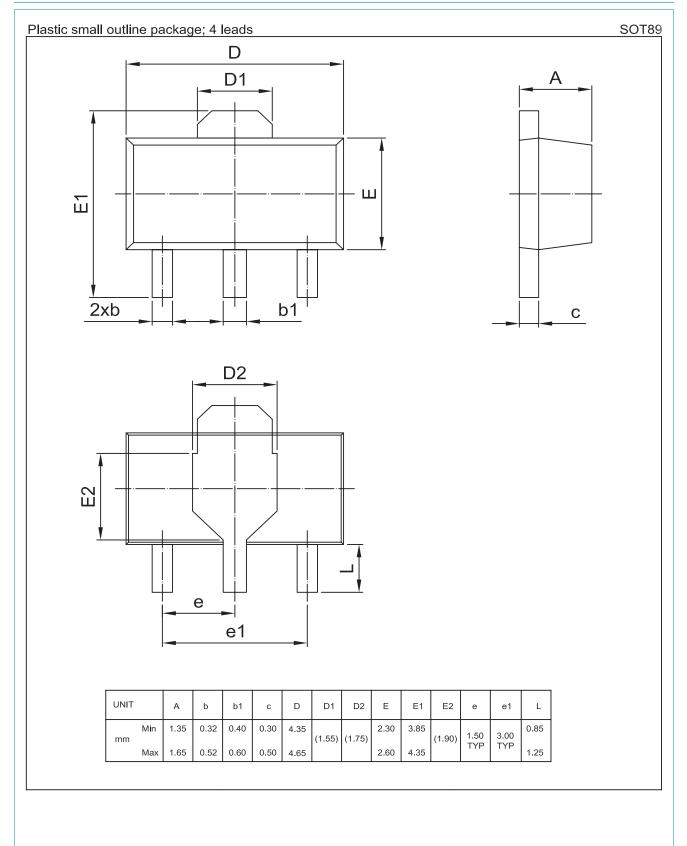


### **WeEn Semiconductors**

NCR100Q-6M



## 11. Package outline



## 12. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

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